Product data sheet

1. General description

Dual Silicon Carbide Schottky diode in a 3-lead TO247 plastic package, designed for high frequency switched-mode power supplies.



2. Features and benefits

- · Extremely fast reverse recovery time
- Low figure of merit (Qc*VF)
- · Highly stable switching performance
- Superior in efficiency to Silicon Diode alternatives
- Reduced losses in associated MOSFET
- Reduced EMI
- · Reduced cooling requirements
- RoHS compliant

3. Applications

- · Power factor correction
- Telecom / Server SMPS
- UPS
- PV inverter
- PC Silverbox
- LED / OLED TV
- Motor Drives

4. Quick reference data

Table 1. Quick reference data

iable I. Qi	uick reference data						
Symbol	Parameter	Conditions	Values		Unit		
Absolute	maximum rating						
V_{RRM}	repetitive peak reverse voltage			12	200		V
I _{O(AV)}	limiting average forward current	δ = 0.5 ; square-wave pulse; T _{mb} ≤ 126 °C; both diodes conducting; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u>	20		Α		
T _j	junction temperature		175		°C		
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
Static ch	aracteristics						
V _F	forward voltage	$I_F = 10 \text{ A}$; $T_j = 25 ^{\circ}\text{C}$; per diode; Fig. 5		-	1.42	1.65	V
		I _F = 10 A; T _j = 150 °C; per diode; <u>Fig. 5</u>		-	1.88	2.3	V
		I _F = 10 A; T _j = 175 °C; per diode; <u>Fig. 5</u>		-	1.97	2.5	V
Dynamic	characteristics					,	
Q _r	recovered charge	$I_F = 10 \text{ A}$; $dI_F/dt = 500 \text{ A/}\mu\text{s}$; $V_R = 400 \text{ V}$; $T_j = 25 ^{\circ}\text{C}$; per diode; Fig. 7		-	25	-	nC

5. Pinning information

Table 2. Pinning information

Pin	Symbol	Description	Simplified outline	Graphic symbol
1	A1	anode		
2	K	cathode	ТОЧ	A1
3	A2	anode		K
mb	mb	mounting base; connected to cathode	1 2 3	sym125

6. Ordering information

Table 3. Ordering information

Type number	Package name	Orderable part number	Packing method	Small packing quantity	Package version	Package issue date
WNSC2D201200CW	TO247	WNSC2D201200CWQ	Tube	30	TO247N	20-July-2016

7. Marking

Table 4. Marking codes

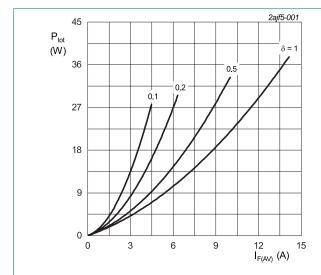
Type number	Marking codes
WNSC2D201200CW	WNSC2D 201200CW

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Values	Unit
V_{RRM}	repetitive peak reverse voltage		1200	V
V_{RWM}	crest working reverse voltage		1200	V
V_R	reverse voltage	DC	1200	V
I _{O(AV)}	limiting average forward current	$δ$ = 0.5; square-wave pulse; $T_{mb} \le 126$ °C; both diodes conducting; Fig. 1; Fig. 2; Fig. 3	20	А
I _{FRM}	repetitive peak forward current	$δ = 0.5$; $t_p = 25 \mu s$; $T_{mb} \le 129 °C$; square-wave pulse; per diode	20	А
I _{FSM}	non-repetitive peak forward current	t_p = 10 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode	72	А
		t_p = 10 µs; $T_{j(init)}$ = 25 °C; square-wave pulse; per diode	850	А
l ² t	I ² t for fusing	sine-wave pulse; $T_{j(init)} = 25 \text{ °C}$; $t_p = 10 \text{ ms}$	26	A ² s
T _{stg}	storage temperature		-55 to 175	°C
T _j	junction temperature		175	°C



$$\begin{split} I_{F(AV)} &= I_{F(RMS)} \times \sqrt{\delta} \\ V_o &= 1.041 \text{ V; R}_s = 0.1148 \text{ }\Omega \end{split}$$

Fig. 1. Forward power dissipation as a function of average forward current; square waveform; maximum values; per diode

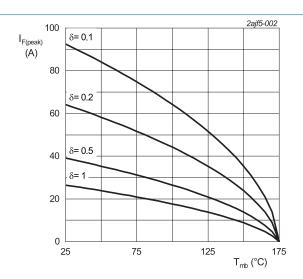
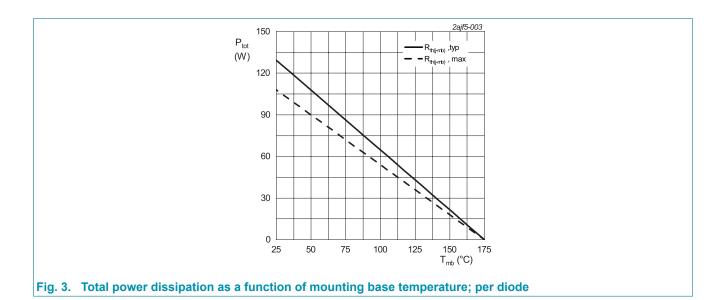


Fig. 2. Current derating as a function of mounting base temperature; per diode



9. Thermal characteristics

Table 6. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
R _{th(j-mb)}	thermal resistance	per diode; Fig. 4	-	1.16	1.39	K/W
	from junction to mounting base	both diodes conducting	-	-	0.73	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	in free air	-	40	-	K/W

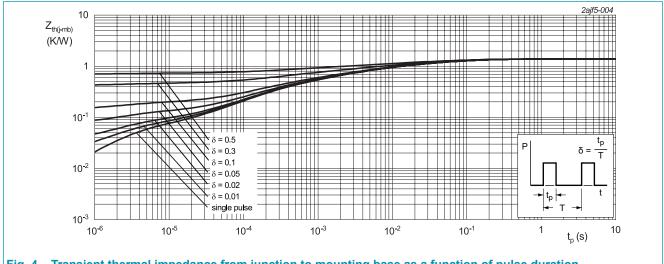
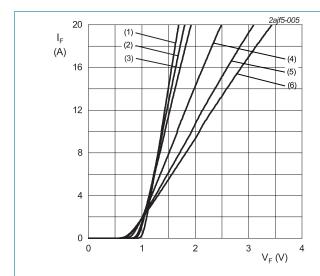


Fig. 4. Transient thermal impedance from junction to mounting base as a function of pulse duration

10. Characteristics

Table 7. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static cha	racteristics					
V _F	forward current	I _F = 10 A; T _j = 25 °C; per diode; <u>Fig. 5</u>	-	1.42	1.65	V
		I _F = 10 A; T _j = 150 °C; per diode; <u>Fig. 5</u>	-	1.88	2.3	V
		I _F = 10 A; T _j = 175 °C; per diode; <u>Fig. 5</u>	-	1.97	2.5	V
I _R	reverse current	V _R = 1200 V; T _j = 25 °C; per diode; <u>Fig. 6</u>	-	3	110	μA
		V _R = 1200 V; T _j = 175 °C; per diode; <u>Fig. 6</u>	-	60		μA
Dynamic	characteristics		'			
Q _r	recovered charge	$I_F = 10 \text{ A}$; $V_R = 400 \text{ V}$; $dI_F/dt = 500 \text{ A}/\mu\text{s}$; $T_j = 25 \text{ °C}$; per diode; Fig. 7	-	25	-	nC
C _d	diode capacitance	f = 1 MHz; V _R = 1 V; T _j = 25 °C	-	490	-	pF
		f = 1 MHz; V _R = 400 V; T _j = 25 °C	-	48	-	pF
		f = 1 MHz; V _R = 800 V; T _j = 25 °C	-	36	-	pF
E _{as}	non-repetitive avalanche energy	I_R = 4.2 A; L = 10 mH; $T_{j(init)}$ = 25 °C; per diode	88	-	-	mJ



 V_o = 1.041 V; R_s = 0.1148 Ω

(1) $T_i = -55$ °C; typical values

(2) T_i = 0 °C; typical values

(3) T_j = 25 °C; typical values

(4) $T_j = 100 \,^{\circ}\text{C}$; typical values

(5) $T_j = 150$ °C; typical values (6) $T_j = 175$ °C; typical values

Fig. 5. Forward current as a function of forward voltage; typical values; per diode

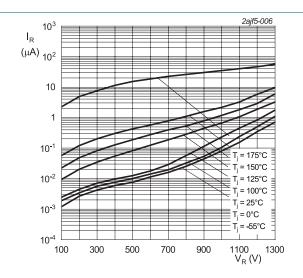
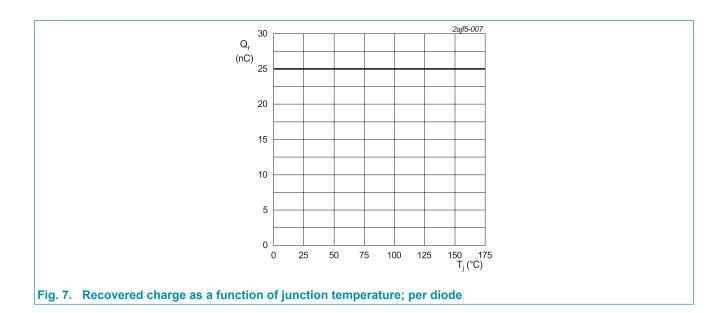
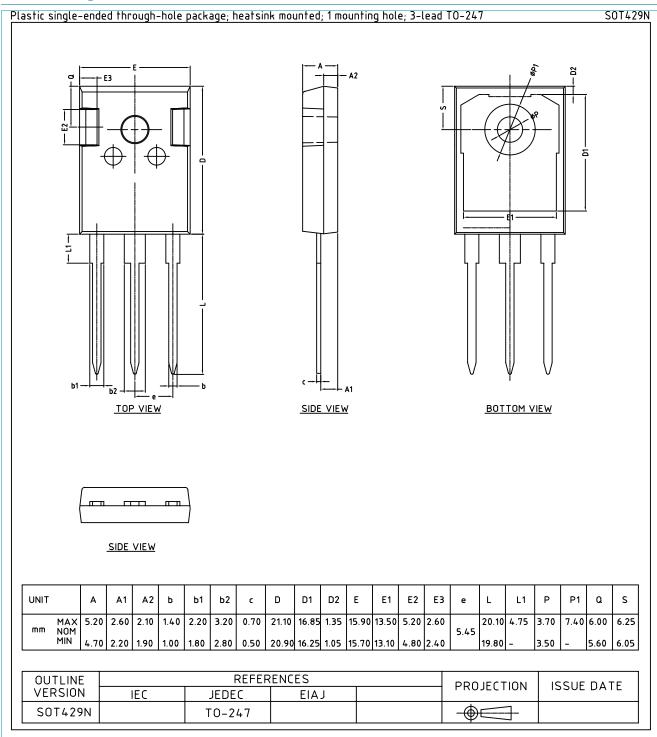


Fig. 6. Reverse leakage current as a function of reverse voltage; typical value; per diode



11. Package outline



12. Legal information

Data sheet status

Document status [1][2]	Product status [3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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13. Contents

1.	General description	′
	Features and benefits	
3.	Applications	′
4.	Quick reference data	′
5.	Pinning information	2
	Ordering information	
	Marking	
	Limiting values	
	Thermal characteristics	
	. Characteristics	
	Package outline	
	. Legal information	
	Contents	

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